

## Standard Rectifier

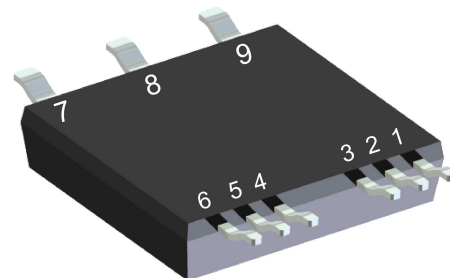
| 3~<br>Rectifier |          |
|-----------------|----------|
| $V_{RRM}$       | = 1800 V |
| $I_{DAV}$       | = 90 A   |
| $I_{FSM}$       | = 350 A  |

ISOPLUS™  
 Surface Mount Power Device  
 3~ Rectifier Bridge

Part number

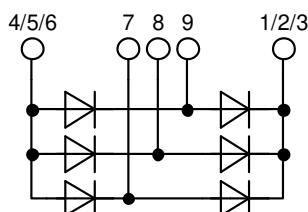
**DMA90U1800LB**

Marking on Product: DMA90U1800LB



Backside: isolated

 E72873



### Features / Advantages:

- Rectifier diode
- Isolated back surface
- Low coupling capacity between pins and heatsink
- Enlarged creepage towards heatsink
- Application friendly pinout
- Low inductive current path
- High reliability

### Applications:

- Line rectifying 50/60 Hz
- Drives
- SMPS
- UPS

### Package: SMPD

- Isolation Voltage: 3000 V~
- Industry convenient outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

### Disclaimer Notice

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| Rectifier  |                                              |                                                   |                                                     | Ratings                        |      |      |                  |
|------------|----------------------------------------------|---------------------------------------------------|-----------------------------------------------------|--------------------------------|------|------|------------------|
| Symbol     | Definition                                   | Conditions                                        |                                                     | min.                           | typ. | max. | Unit             |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$                     |                                                     |                                |      | 1900 | V                |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$                     |                                                     |                                |      | 1800 | V                |
| $I_R$      | reverse current                              | $V_R = 1800\text{ V}$                             | $T_{VJ} = 25^{\circ}\text{C}$                       |                                |      | 40   | $\mu\text{A}$    |
|            |                                              | $V_R = 1800\text{ V}$                             | $T_{VJ} = 150^{\circ}\text{C}$                      |                                |      | 1.5  | mA               |
| $V_F$      | forward voltage drop                         | $I_F = 30\text{ A}$                               | $T_{VJ} = 25^{\circ}\text{C}$                       |                                |      | 1.26 | V                |
|            |                                              | $I_F = 90\text{ A}$                               |                                                     |                                |      | 1.79 | V                |
|            |                                              | $I_F = 30\text{ A}$                               | $T_{VJ} = 150^{\circ}\text{C}$                      |                                |      | 1.20 | V                |
|            |                                              | $I_F = 90\text{ A}$                               |                                                     |                                |      | 1.93 | V                |
| $I_{DAV}$  | bridge output current                        | $T_C = 110^{\circ}\text{C}$<br>rectangular        | $T_{VJ} = 175^{\circ}\text{C}$<br>$d = \frac{1}{3}$ |                                |      | 90   | A                |
| $V_{F0}$   | threshold voltage                            | } for power loss calculation only                 |                                                     | $T_{VJ} = 175^{\circ}\text{C}$ |      | 0.81 | V                |
| $r_F$      | slope resistance                             |                                                   |                                                     |                                |      | 12.7 | m $\Omega$       |
| $R_{thJC}$ | thermal resistance junction to case          |                                                   |                                                     |                                |      | 1.1  | K/W              |
| $R_{thCH}$ | thermal resistance case to heatsink          |                                                   |                                                     |                                | 0.4  |      | K/W              |
| $P_{tot}$  | total power dissipation                      | $T_C = 25^{\circ}\text{C}$                        |                                                     |                                |      | 135  | W                |
| $I_{FSM}$  | max. forward surge current                   | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$  | $T_{VJ} = 45^{\circ}\text{C}$                       |                                |      | 350  | A                |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$                                  |                                |      | 380  | A                |
|            |                                              | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$  | $T_{VJ} = 150^{\circ}\text{C}$                      |                                |      | 300  | A                |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$                                  |                                |      | 320  | A                |
| $I^2t$     | value for fusing                             | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$  | $T_{VJ} = 45^{\circ}\text{C}$                       |                                |      | 615  | A <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$                                  |                                |      | 600  | A <sup>2</sup> s |
|            |                                              | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$  | $T_{VJ} = 150^{\circ}\text{C}$                      |                                |      | 450  | A <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$                                  |                                |      | 425  | A <sup>2</sup> s |
| $C_J$      | junction capacitance                         | $V_R = 400\text{ V}; f = 1\text{ MHz}$            |                                                     |                                | 11   |      | pF               |

| Package    SMPD      |                                                              |                      |                                         | Ratings |      |      |      |
|----------------------|--------------------------------------------------------------|----------------------|-----------------------------------------|---------|------|------|------|
| Symbol               | Definition                                                   | Conditions           |                                         | min.    | typ. | max. | Unit |
| I <sub>RMS</sub>     | RMS current                                                  | per terminal         |                                         |         |      | 100  | A    |
| T <sub>VJ</sub>      | virtual junction temperature                                 |                      |                                         | -55     |      | 175  | °C   |
| T <sub>op</sub>      | operation temperature                                        |                      |                                         | -55     |      | 150  | °C   |
| T <sub>stg</sub>     | storage temperature                                          |                      |                                         | -55     |      | 150  | °C   |
| Weight               |                                                              |                      |                                         |         | 8.5  |      | g    |
| F <sub>C</sub>       | mounting force with clip                                     |                      |                                         | 40      |      | 130  | N    |
| d <sub>Spp/App</sub> | creepage distance on surface   striking distance through air | terminal to terminal |                                         | 1.6     |      |      | mm   |
| d <sub>Spb/Apb</sub> |                                                              | terminal to backside |                                         | 4.0     |      |      | mm   |
| V <sub>ISOL</sub>    | isolation voltage                                            | t = 1 second         | 50/60 Hz, RMS; I <sub>ISOL</sub> ≤ 1 mA | 3000    |      |      | V    |
|                      |                                                              | t = 1 minute         |                                         | 2500    |      |      | V    |



### Part description

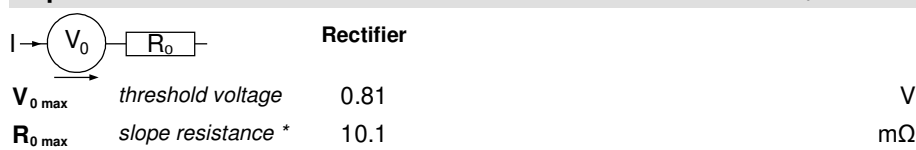
D = Diode  
 M = Standard Rectifier  
 A = (up to 1800V)  
 90 = Current Rating [A]  
 U = 3- Rectifier Bridge  
 1800 = Reverse Voltage [V]  
 LB = SMPD-B

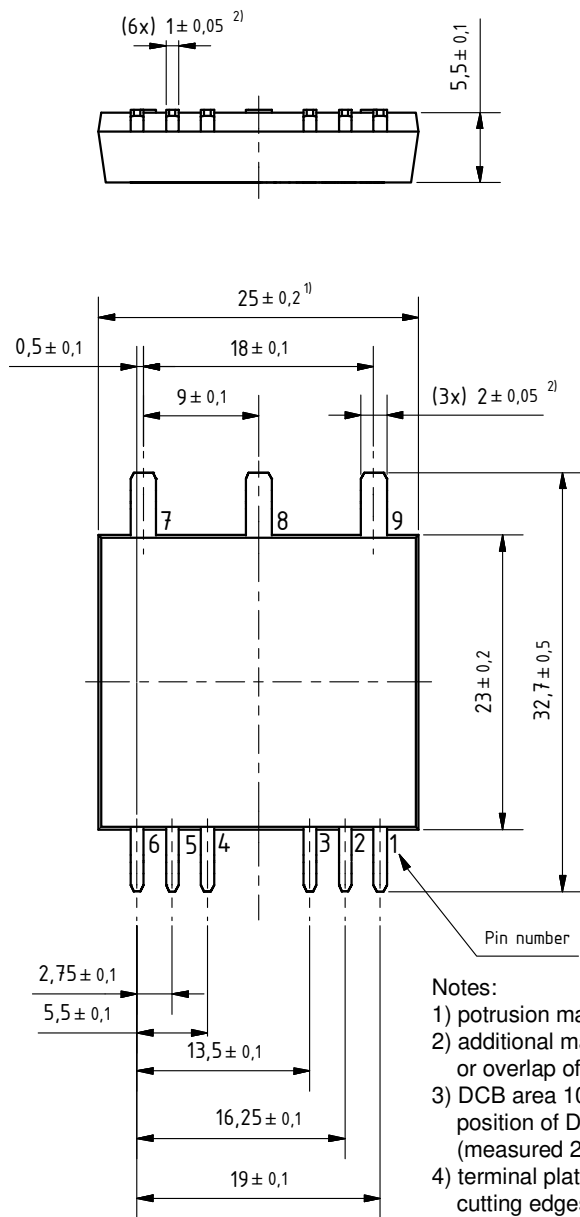
| Ordering    | Ordering Number  | Marking on Product | Delivery Mode | Quantity | Code No. |
|-------------|------------------|--------------------|---------------|----------|----------|
| Standard    | DMA90U1800LB-TUB | DMA90U1800LB       | Tube          | 20       | 517130   |
| Alternative | DMA90U1800LB-TRR | DMA90U1800LB       | Tape & Reel   | 200      | 524497   |

### Equivalent Circuits for Simulation

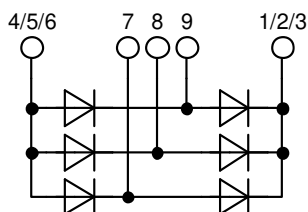
\* on die level

$T_{VJ} = 175^\circ\text{C}$



**Outlines SMPD**
**A ( 8 : 1 )**

**Notes:**

- 1) potrusion may add 0.2 mm max. on each side
- 2) additional max. 0.05 mm per side by punching misalignement or overlap of dam bar or bending compression
- 3) DCB area 10 to 50  $\mu\text{m}$  convex;  
position of DCB area in relation to plastic rim:  $\pm 25 \mu\text{m}$  (measured 2 mm from Cu rim)
- 4) terminal plating: 0.2 - 1  $\mu\text{m}$  Ni + 10 - 25  $\mu\text{m}$  Sn (gal v.)  
cutting edges may be partially free of plating



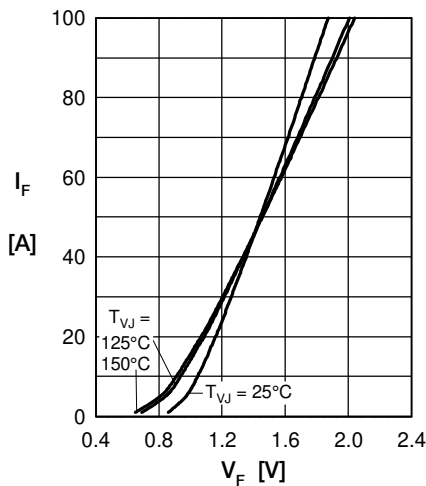
**Rectifier**


Fig. 1 Forward current vs. voltage drop per diode

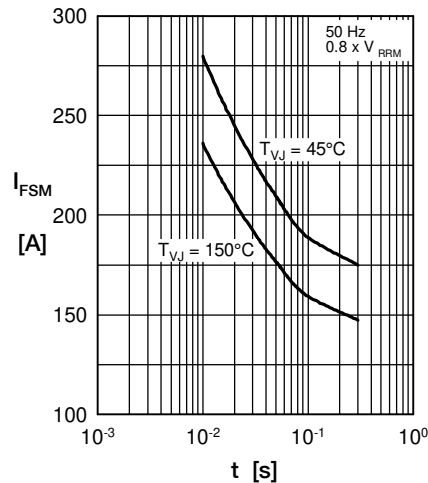


Fig. 2 Surge overload current vs. time per diode

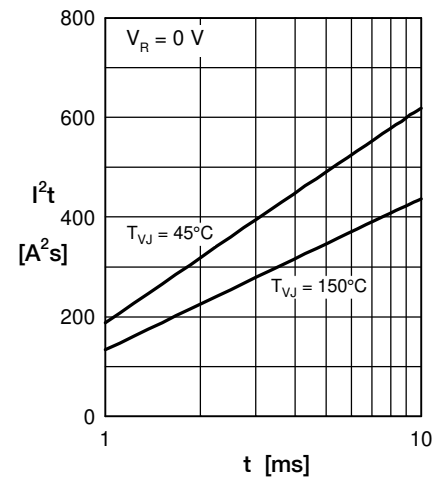


Fig. 3  $I^2t$  vs. time per diode

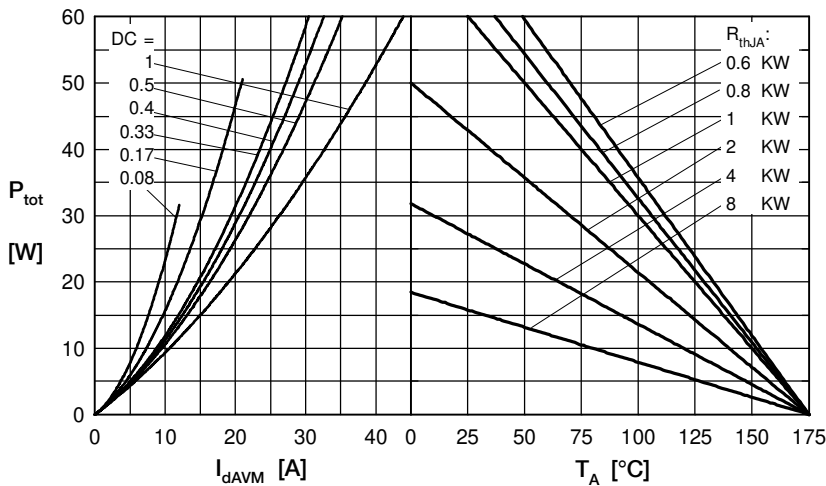


Fig. 4 Power dissipation vs. forward current and ambient temperature per diode

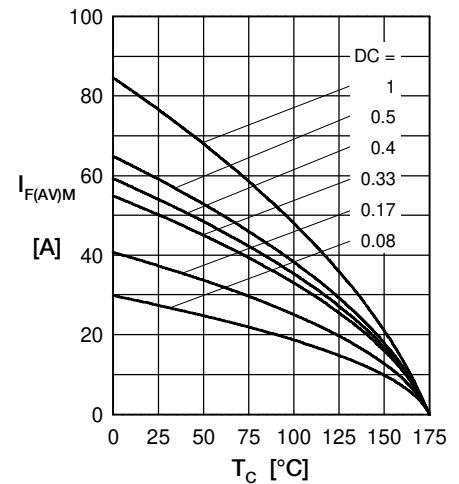


Fig. 5 Max. forward current vs. case temperature per diode

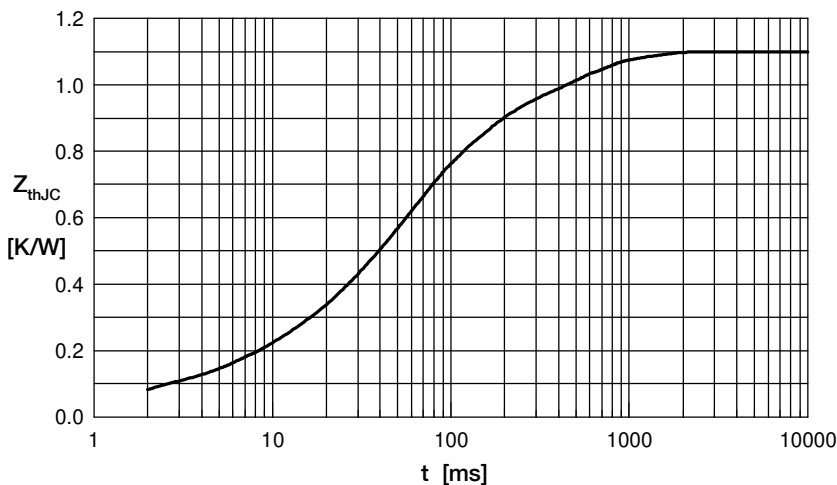


Fig. 6 Transient thermal impedance junction to case vs. time per diode

Constants for  $Z_{thJC}$  calculation:

| i | $R_{th}$ (K/W) | $t_i$ (s) |
|---|----------------|-----------|
| 1 | 0.030          | 0.0003    |
| 2 | 0.072          | 0.0045    |
| 3 | 0.092          | 0.0530    |
| 4 | 0.606          | 0.0520    |
| 5 | 0.300          | 0.4000    |